NSN 5962-01-171-5596

Memory Microcircuit - Page 1 of 1



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| Body Length: | |
|----------------------|--|
| 0.520 inches | |
| Body Width: | |
| 0.390 inches | |
| Body Height: | |
| 0.085 inches | |
| Maximum Power | Dissipation Rating: |
| 715.0 milliwatts | |
| Operating Tempur | ature Range: |
| -55.0/+125.0 degre | es celsius |
| Storage Tempurat | ure Range: |
| -65.0/+150.0 degre | es celsius |
| Features Provided | : |
| Bipolar and prograr | nmable and 3-state output |
| Inclosure Material | |
| Ceramic | |
| Inclosure Configu | ration: |
| Flat pack | |
| Output Logic Forn | n: |
| Transistor-transisto | r logic |
| Input Circuit Patte | rn: |
| 12 input | |
| Terminal Surface | Treatment: |
| Solder | |
| Voltage Rating An | d Type Per Characteristic: |
| -0.5 volts power sc | urce and 7.0 volts power source |
| Time Rating Per C | hacteristic: |
| 125.00 nanosecond | Is propagation delay time, low to high level output and 125.00 nanoseconds propagation delay time, high to low lev |
| output | |
| Memory Device Ty | rpe: |
| Rom | |
| Test Data Docume | int: |
| 82577-932892 stan | dard (includes industry or association standards, individual manufactureer standards, etc.). |
| Terminal Type And | d Quantity: |
| 18 flat leads | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| Yes - demil/mli | |
| Fiig: | |
| A458a0 | |